Preferred Device

Silicon Controlled Rectifiers

Reverse Blocking Thyristors

Designed primarily for half-wave ac control applications, such as motor controls, heating controls and power supply crowbar circuits.

Features

- Glass Passivated Junctions with Center Gate Fire for Greater Parameter Uniformity and Stability
- Small, Rugged, Thermowatt Constructed for Low Thermal Resistance, High Heat Dissipation and Durability
- Blocking Voltage to 800 Volts
- 300 A Surge Current Capability
- Pb-Free Packages are Available

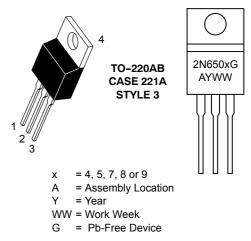


Littelfuse.com

SCRs 25 AMPERES RMS 50 thru 800 VOLTS







	PIN ASSIGNMENT
1	Cathode
2	Anode
3	Gate
4	Anode

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

Preferred devices are recommended choices for future use and best overall value.

MAXIMUM RATINGS ($T_J = 25^{\circ}C$ unless otherwise noted)

Rating	Symbol	Value	Unit
*Peak Repetitive Off-State Voltage (Note 1) (Gate Open, Sine Wave 50 to 60 Hz, T _J = 25 to 125°C) 2N6504 2N6505 2N6507 2N6508 2N6509	V _{DRM,} V _{RRM}	50 100 400 600 800	V
On-State Current RMS (180° Conduction Angles; T _C = 85°C)	I _{T(RMS)}	25	А
Average On-State Current (180° Conduction Angles; T _C = 85°C)	I _{T(AV)}	16	А
Peak Non-repetitive Surge Current (1/2 Cycle, Sine Wave 60 Hz, T_J = 100°C)	I _{TSM}	250	А
Forward Peak Gate Power (Pulse Width \leq 1.0 μ s, T _C = 85°C)	P _{GM}	20	W
Forward Average Gate Power (t = 8.3 ms, T _C = 85°C)	P _{G(AV)}	0.5	W
Forward Peak Gate Current (Pulse Width \leq 1.0 μ s, T _C = 85°C)	I _{GM}	2.0	А
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Ratings apply for zero or negative gate voltage; however, positive gate voltage shall not be applied concurrent with negative potential on the anode. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Мах	Unit
*Thermal Resistance, Junction-to-Case	$R_{ ext{ heta}JC}$	1.5	°C/W
*Maximum Lead Temperature for Soldering Purposes 1/8 in from Case for 10 Seconds	TL	260	°C

ELECTRICAL CHARACTERISTICS (T_C = 25°C unless otherwise noted.)

Symbol	Min	Тур	Max	Unit
I _{DRM} , Irrm	-	-	10 2.0	μA mA
	-		-	
V _{TM}	-	-	1.8	V
I _{GT}	-	9.0 -	30 75	mA
V _{GT}	-	1.0	1.5	V
V _{GD}	0.2	-	-	V
Ι _Η	-	18 -	40 80	mA
t _{gt}	-	1.5	2.0	μs
tq		15 35		μs
	V _{TM} I _{GT} V _{GD} I _H t _{gt}	IRRM - VTM - IGT - VGT - VGD 0.2 IH - - - tgt -	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	$\begin{array}{c ccccccccccccccccccccccccccccccccccc$

Critical Rate of Rise of Off-State Voltage (Gate Open, Rated V_{DRM} , Exponential Waveform)	dv/dt	-	50	-	V/μs

*Indicates JEDEC Registered Data.

2. Pulse Test: Pulse Width \leq 300 $\mu s,$ Duty Cycle \leq 2%.

Voltage Current Characteristic of SCR

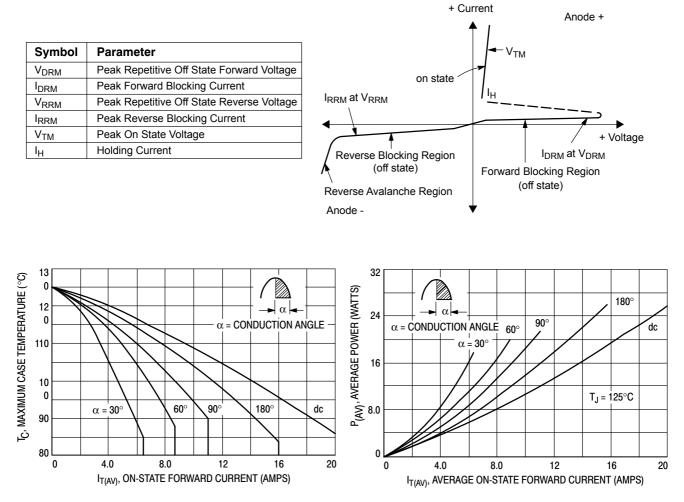


Figure 1. Average Current Derating

Figure 2. Maximum On-State Power Dissipation

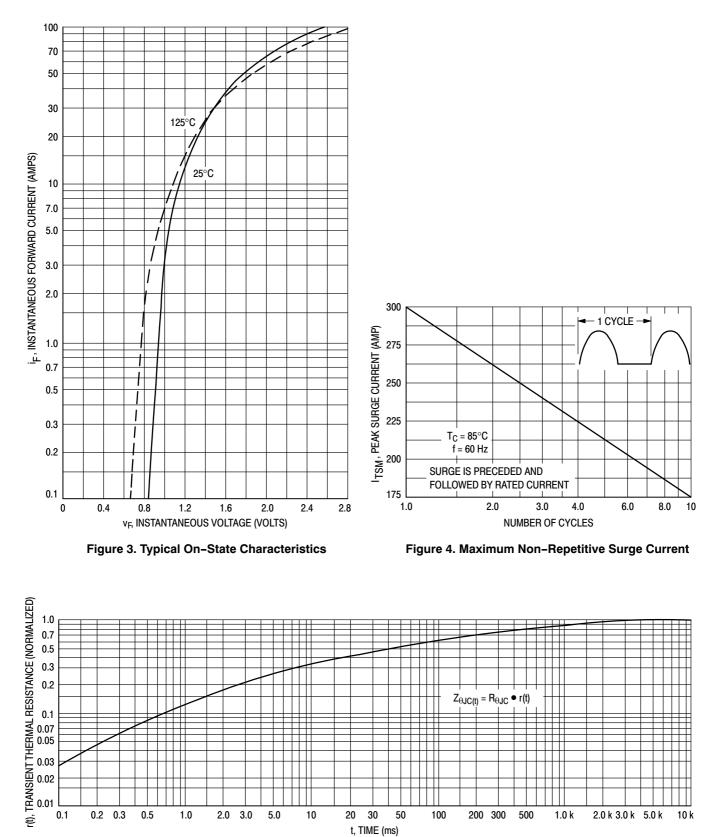
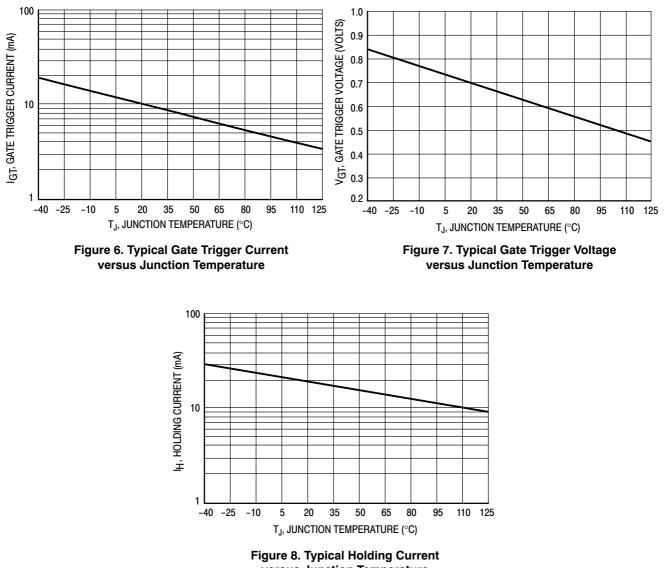


Figure 5. Thermal Response

TYPICAL TRIGGER CHARACTERISTICS



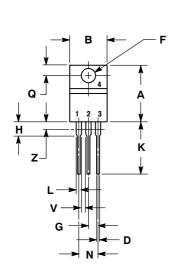
versus Junction Temperature

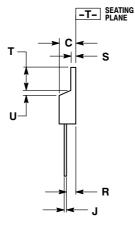
ORDERING INFORMATION

Device	Package	Shipping
2N6504	TO-220AB	
2N6504G	TO-220AB (Pb-Free)	500 Units / Box
2N6505	TO-220AB	SUU UNITS / BOX
2N6505G	TO-220AB (Pb-Free)	
2N6505T	TO-220AB	
2N6505TG	TO-220AB (Pb-Free)	50 Units / Rail
2N6507	TO-220AB	
2N6507G	TO-220AB (Pb-Free)	500 Units / Box
2N6507T	TO-220AB	
2N6507TG	TO-220AB (Pb-Free)	50 Units / Rail
2N6508	TO-220AB	
2N6508G	TO-220AB (Pb-Free)	500 Units / Box
2N6508TG	TO-220AB (Pb-Free)	50 Units / Rail
2N6509	TO-220AB	
2N6509G	TO-220AB (Pb-Free)	500 Units / Box
2N6509T	TO-220AB	
2N6509TG	TO-220AB (Pb-Free)	50 Units / Rail

PACKAGE DIMENSIONS

TO-220AB CASE 221A-07 **ISSUE AA**





NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI

DIMENSIONING AND TOLEHANCING PEH ANS Y14.5M, 1982.
CONTROLLING DIMENSION: INCH.
DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INCHES MILLIME			IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
c	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
L	0.014	0.022	0.36	0.55
Κ	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
Ν	0.190	0.210	4.83	5.33
Ø	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
Т	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
۷	0.045		1.15	
Ζ		0.080		2.04

STYLE 3: PIN 1. CATHODE

2. ANODE GATE 3.

4. ANODE

Littelfuse products are not designed for, and shall not be used for, any purpose (including, without limitation, automotive, military, aerospace, medical, life-saving, life-sustaining or nuclear facility applications, devices intended for surgical implant into the body, or any other application in which the failure or lack of desired operation of the product may result in personal injury, death, or property damage) other than those expressly set forth in applicable Littelfuse product documentation. Warranties granted by Littelfuse shall be deemed void for products used for any purpose not expressly set forth in applicable Littelfuse documentation. Littelfuse shall not be liable for any claims or damages arising out of products used in applications not expressly intended by Littelfuse as set forth in applicable Littelfuse documentation. The sale and use of Littelfuse products is subject to Littelfuse Terms and Conditions of Sale, unless otherwise agreed by Littelfuse.

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